



1N4001 - 1N4007

1.0 AMPS. Silicon Rectifiers

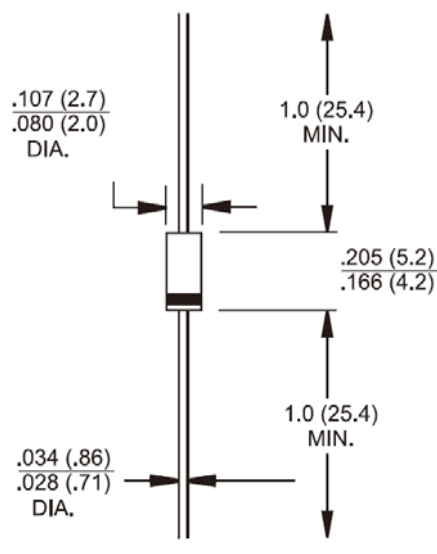
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Features

- ◇ High efficiency, Low VF
- ◇ High current capability
- ◇ High reliability
- ◇ High surge current capability
- ◇ Low power loss
- ◇ Green compound with suffix "G" on packing code & prefix "G" on datecode

Mechanical Data

- ◇ Case: Molded plastic
- ◇ Epoxy: UL 94V-0 rate flame retardant
- ◇ Lead: Pure tin plated, lead free, solderable per MIL-STD-202, Method 208 guaranteed
- ◇ Polarity: Color band denotes cathode
- ◇ High temperature soldering guaranteed: 260°C/10s / .375", (9.5mm) lead lengths at 5 lbs, (2.3kg) tension
- ◇ Weight: 0.35 grams



Dimensions in inches and (millimeters)

Marking Diagram



- 1N400X = Specific Device Code
- G = Green Compound
- Y = Year
- WW = Work Week

Maximum Ratings and Electrical Characteristics

Rating at 25 °C ambient temperature unless otherwise specified.

Single phase, half wave, 60 Hz, resistive or inductive load.

For capacitive load, derate current by 20%

Type Number	Symbol	1N 4001	1N 4002	1N 4003	1N 4004	1N 4005	1N 4006	1N 4007	Unit
Maximum Repetitive Peak Reverse Voltage	V_{RRM}	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	V_{RMS}	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	V_{DC}	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Current .375"(9.5mm) Lead Length @ $T_A=75^\circ C$	$I_{F(AV)}$	1							A
Peak Forward Surge Current, 8.3 ms Single Half Sine-wave Superimposed on Rated Load (JEDEC method)	I_{FSM}	30							A
Rating for Fusing (t<8.3ms)	I^2T	3.7							A ² S
Maximum Instantaneous Forward Voltage (Note 1) @ 1 A	V_F	1.0							V
Maximum Reverse Current @ Rated VR $T_A=25^\circ C$ $T_A=125^\circ C$	I_R	5 50							μA
Maximum Full load Reverse Current, Full cycle Average .375"(9.5mm) Lead Length @ $T_A=75^\circ C$	$I_{R(AV)}$	30							μA
Typical Junction Capacitance (Note 2)	C_j	10							pF
Typical Thermal Resistance	$R_{\theta JA}$ $R_{\theta JC}$ $R_{\theta JL}$	65 6 15							$^\circ C/W$
Operating Temperature Range	T_J	- 65 to + 150							$^\circ C$
Storage Temperature Range	T_{STG}	- 65 to + 150							$^\circ C$

Note1: Pulse Test with PW=300 usec, 1% Duty Cycle

Note2: Measured at 1 MHz and Applied Reverse Voltage of 4.0V D.C.

RATINGS AND CHARACTERISTIC CURVES (1N4001 THRU 1N4007)

FIG.1 MAXIMUM FORWARD CURRENT DERATING CURVE

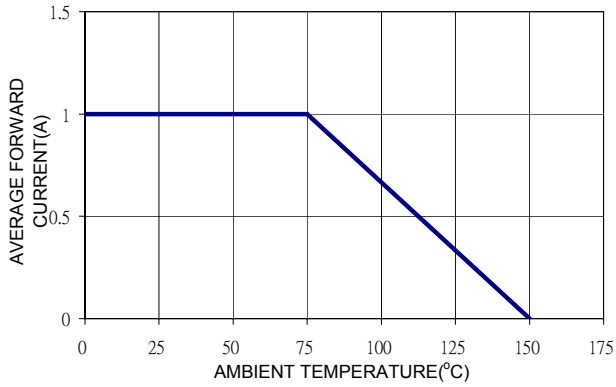


FIG. 2 MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT

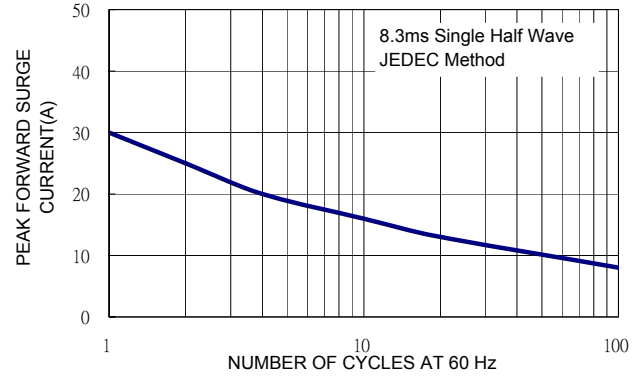


FIG. 3 TYPICAL FORWARD CHARACTERISTICS

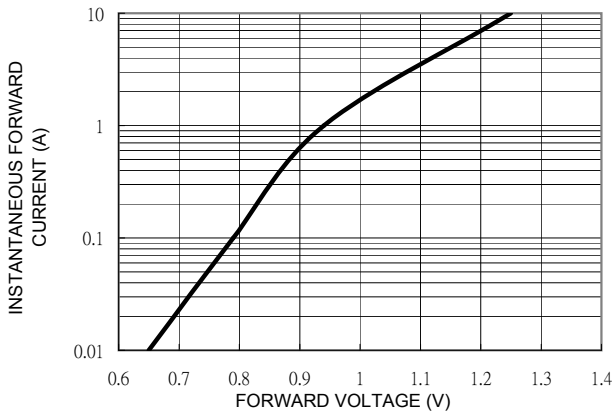


FIG. 4 TYPICAL REVERSE CHARACTERISTICS

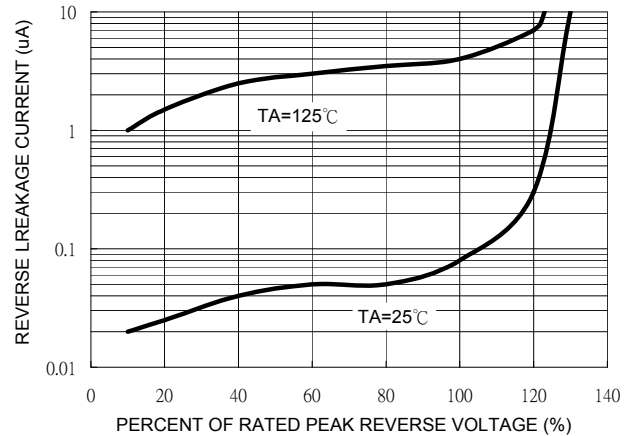


FIG. 5 TYPICAL JUNCTION CAPACITANCE

